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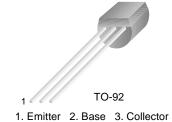
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PN3567

NPN General Purpose Amplifier

- This device is for use as a medium amplifier and switch requiring collector currents up 300mA.
- Sourced from process 19.



Absolute Maximum Ratings T_A=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|--|------------|-------|
| V _{CEO} | Collector-Emitter Voltage | 40 | V |
| V _{CBO} | Collector-Base Voltage | 80 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current - Continuous | 600 | mA |
| $T_{J_i}T_{STG}$ | Operating and Storage Junction Temperature Range | - 55 ~ 150 | °C |

Electrical Characteristics $T_A=25^{\circ}C$ unless otherwise noted

| Parameter | Test Condition | Min. | Тур. | Max. | Units |
|--|---|---|--|--|--|
| Off Characteristics | | | | | |
| Collector-Emitter Breakdown Voltage * | I _C = 30mA, I _B = 0 | 40 | | | V |
| Collector-Base Breakdown Voltage | $I_C = 100 \mu A, I_E = 0$ | 80 | | | V |
| Emitter-Base Breakdown Voltage | $I_E = 10\mu A, I_C = 0$ | 5 | | | V |
| Collector Cut-off Current | $V_{CB} = 40V, I_{E} = 0$ | | | 50 | nA |
| | $V_{CB} = 40V, I_{E} = 0, T_{A} = 75^{\circ}C$ | | | 5 | μΑ |
| Emitter Cut-off Current | $V_{EB} = 4V, I_C = 0$ | | | 25 | nA |
| On Characteristics | | | | | |
| DC Current Gain | V _{CE} = 1V, I _C = 150mA | 40 | | 120 | |
| | $V_{CE} = 1V$, $I_C = 30mA$ | 40 | | | |
| Collector-Emitter Saturation Voltage * | I _C = 150mA, I _B = 15mA | | | 0.25 | V |
| Base-Emitter On Voltage | $V_{CE} = 1V, I_{C} = 150mA$ | | | 1.1 | V |
| Small Signal Characteristics | | | | | |
| Output Capacitance | $V_{CB} = 10V, I_{E} = 0$ | | | 20 | pF |
| Input Capacitance | $V_{EB} = 0.5V, I_{C} = 0$ | | | 80 | |
| | Collector-Emitter Breakdown Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current Cteristics DC Current Gain Collector-Emitter Saturation Voltage * Base-Emitter On Voltage all Characteristics Output Capacitance | Collector-Emitter Breakdown Voltage * $I_C = 30$ mA, $I_B = 0$ Collector-Base Breakdown Voltage $I_C = 100$ µA, $I_C = 0$ Emitter-Base Breakdown Voltage $I_E = 10$ µA, $I_C = 0$ Collector Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ Emitter Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ Emitter Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ Emitter Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ Exteristics DC Current Gain $V_{CE} = 1$ V, $I_C = 150$ mA $V_{CE} = 1$ V, $I_C = 30$ mA Collector-Emitter Saturation Voltage * $I_C = 150$ mA, $I_D = 15$ mA Base-Emitter On Voltage $V_{CE} = 1$ V, $I_C = 150$ mA Final Characteristics Output Capacitance $V_{CB} = 10$ V, $I_C = 0$ | Collector-Emitter Breakdown Voltage * $I_C = 30$ mA, $I_B = 0$ 40 Collector-Base Breakdown Voltage $I_C = 100$ µA, $I_C = 0$ 80 Emitter-Base Breakdown Voltage $I_C = 100$ µA, $I_C = 0$ 5 Collector Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ 7 Emitter Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ 7 Emitter Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ 7 Emitter Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ 7 Emitter Cut-off Current $V_{CB} = 40$ V, $I_C = 0$ 7 Collector Current Gain $V_{CE} = 1$ V, $I_C = 150$ mA 40 Collector-Emitter Saturation Voltage * $I_C = 150$ mA, $I_B = 15$ mA Base-Emitter On Voltage $V_{CE} = 1$ V, $I_C = 150$ mA all Characteristics Output Capacitance $V_{CB} = 10$ V, $I_C = 0$ | Collector-Emitter Breakdown Voltage * $I_C = 30 \text{mA}$, $I_B = 0$ 40 Collector-Base Breakdown Voltage $I_C = 100 \mu A$, $I_C = 0$ 80 Emitter-Base Breakdown Voltage $I_C = 100 \mu A$, $I_C = 0$ 5 Collector Cut-off Current $I_C = 0$ 5 Emitter Cut-off Current $I_C = 0$ 7 Emitter Cut-off Current $I_C = 0$ 7 | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ |

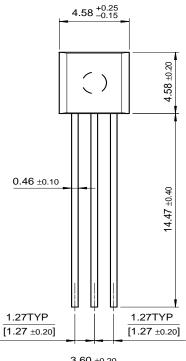
* Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2.0%

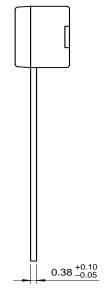
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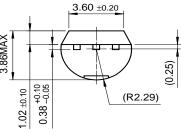
| Thermal Characteristics T _A =25°C unless otherwise noted | | | |
|---|--|----------|-------------|
| Symbol | Parameter | Max. | Units |
| P _D | Total Device Dissipation Derate above 25°C | 625 5 | mW mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 83.3 | °C/W |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | 200 | °C/W |

Package Dimensions

TO-92







Dimensions in Millimeters

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| CoolFET™ | FASTr™ | MicroFET™ | PowerTrench [®] | SuperSOT™-6 |
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Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|---------------------------|---|
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